

Features

- Supply Voltage: 2.5 V to 5.5 V
- Offset Voltage: 5 mV Maximum
- Bandwidth: 1.5 MHz, Slew Rate: 0.7 V/ μ s
- Low Power: 100 μ A per channel
- Rail-to-Rail Input and Output
- Low 1/f Noise: 22 nV/ $\sqrt{\text{Hz}}$ at 1 kHz
- -40°C to 125°C Operation Temperature Range

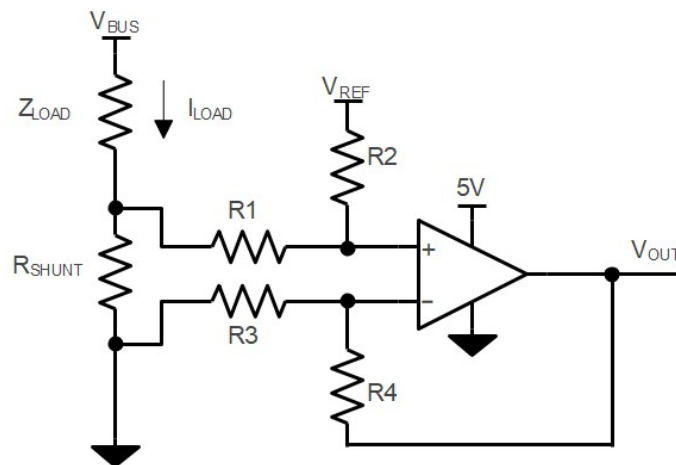
Applications

- Instrumentation
- Motor Control
- Industrial Control

Description

The LMV358X series of products are CMOS dual RRIO op-amps with low offset, low power, and stable high frequency response. They incorporate 3PEAK's proprietary and patented design techniques to achieve very good AC performance with 1.5-MHz bandwidth, 0.7-V/ μ s slew rate and low distortion while drawing only 100 μ A of quiescent current per amplifier. The input common-mode voltage range extends 100-mV beyond V^- and V^+ , and the outputs swing rail-to-rail. The LMV358X family can be used as plug-in replacements for many commercially available op-amps to reduce power and improve input/output range and performance.

Typical Application Circuit



$$V_{\text{OUT}} = (I_{\text{LOAD}} \times R_{\text{SHUNT}}) \times (R_2 / R_1) + V_{\text{REF}}$$

$$\text{When } R_3 = R_1, R_2 = R_4, R_{\text{SHUNT}} \ll R_1$$

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Revision History

Date	Revision	Notes
2023-09-04	Rev.A.0	Initial release.

Pin Configuration and Functions

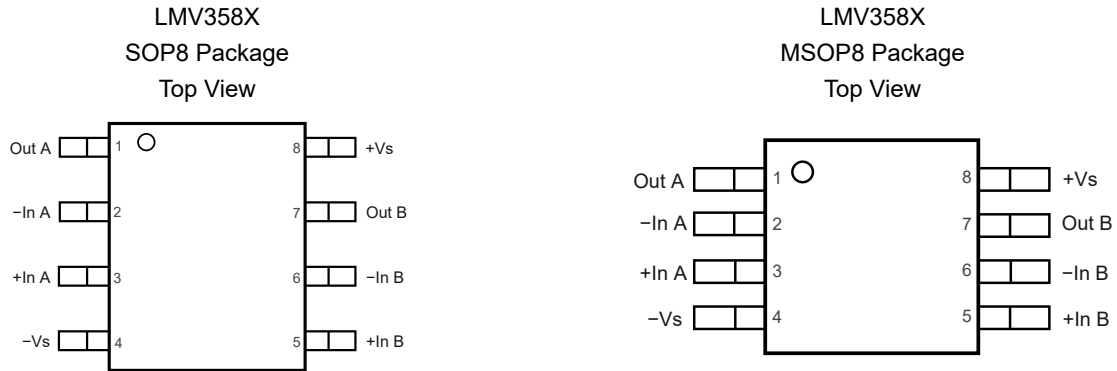


Table 1. Pin Functions: LMV358X

Pin No.	Name	I/O	Description
1	Out A	O	Output
2	-In A	I	Inverting input
3	+In A	I	Noninverting input
4	-Vs	-	Negative power supply
5	+In B	I	Noninverting input
6	-In B	I	Inverting input
7	Out B	O	Output
8	+Vs		Positive power supply

Specifications

Absolute Maximum Ratings

Over operating ambient temperature (unless otherwise noted) ⁽¹⁾

Parameter		Min	Max	Unit
	Supply Voltage, (+V _S) – (–V _S)		6.5	V
	Input Voltage	(–V _S) – 0.3	(+V _S) + 0.5	V
	Differential Input Voltage	(–V _S) – (+V _S)	(+V _S) – (–V _S)	V
	Input Current: +IN, –IN ⁽²⁾	–10	10	mA
	Output Voltage	(–V _S) – 0.3	(+V _S) + 0.3	V
	Output Short-Circuit Duration ⁽³⁾		Infinite	
T _J	Maximum Junction Temperature		150	°C
T _A	Operating Temperature Range	–40	125	°C
T _{STG}	Storage Temperature Range	–65	150	°C
T _L	Lead Temperature (Soldering 10 sec)		260	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.
- (2) The inputs are protected by ESD protection diodes to each power supply. If the input extends more than 300 mV beyond the power supply, the input current should be limited to less than 10 mA.
- (3) A heat sink may be required to keep the junction temperature below the absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted. Thermal resistance varies with the amount of PC board metal connected to the package. The specified values are for short traces connected to the leads.

ESD, Electrostatic Discharge Protection

Parameter		Condition	Minimum Level	Unit
HBM	Human Body Model ESD	ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	6	kV
CDM	Charged Device Model ESD	ANSI/ESDA/JEDEC JS-002 ⁽²⁾	1.5	kV

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

Recommended Operating Conditions

Parameter		Min	Typ	Max	Unit
V _S	Supply Voltage, (+V _S) – (–V _S)	2.5		5.5	V
T _A	Operating Temperature Range	–40		125	°C

Thermal Information

Package Type	θ _{JA}	θ _{JC}	Unit
SOP8	158	43	°C/W

5-V, Rail-to-Rail Input/Output, 1.5-MHz Op Amp

Package Type	θ_{JA}	θ_{JC}	Unit
MSOP8	210	45	$^{\circ}\text{C/W}$

5-V, Rail-to-Rail Input/Output, 1.5-MHz Op Amp
Electrical Characteristics

 All test condition: $V_S = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$, unless otherwise noted.

Parameter		Conditions	Min	Typ	Max	Unit
Power Supply						
V_S	Supply Voltage Range		2.5		5.5	V
I_Q	Quiescent Current per Amplifier			100	160	μA
		$T_A = -40^\circ\text{C}$ to 125°C			190	μA
PSRR	Power Supply Rejection Ratio	$V_S = 2.5\text{ V}$ to 5.5 V	80	110		dB
		$V_S = 2.5\text{ V}$ to 5.5 V , $T_A = -40^\circ\text{C}$ to 125°C	75			dB
Input Characteristics						
V_{OS}	Input Offset Voltage	$V_{CM} = 0\text{ V}$ to 3 V	1	1.2	5	mV
		$V_{CM} = 0\text{ V}$ to 3 V , $T_A = -40^\circ\text{C}$ to 125°C	0.15		5.6	mV
		$V_{CM} = 3\text{ V}$ to 5 V	-5	1.2	7.4	mV
		$V_{CM} = 3\text{ V}$ to 5 V , $T_A = -40^\circ\text{C}$ to 125°C	-5.6		11	mV
$V_{OS\ TC}$	Input Offset Voltage Drift ⁽¹⁾			1		$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current ⁽¹⁾	$V_{CM} = 2.5\text{ V}$	-300	10	300	pA
		$V_{CM} = 2.5\text{ V}$, $T_A = -40^\circ\text{C}$ to 125°C	-5		5	nA
I_{OS}	Input Offset Current ⁽¹⁾	$V_{CM} = 2.5\text{ V}$	-300	10	300	pA
		$V_{CM} = 2.5\text{ V}$, $T_A = -40^\circ\text{C}$ to 125°C	-5		5	nA
C_{IN}	Input Capacitance ⁽²⁾	Differential Mode		6		pF
		Common Mode		8		pF
A_v	Open-loop Voltage Gain	$V_O = 0.1\text{ V}$ to 4.9 V	80	100		dB
		$V_O = 0.1\text{ V}$ to 4.9 V , $T_A = -40^\circ\text{C}$ to 125°C	75			dB
V_{CMR}	Common-mode Input Voltage Range	$T_A = -40^\circ\text{C}$ to 125°C	$(-V_S)-0.1$		$(+V_S)+0.1$	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0\text{ V}$ to 5 V	60	80		dB
		$V_{CM} = 0\text{ V}$ to 5 V , $T_A = -40^\circ\text{C}$ to 125°C	55			dB
		$V_{CM} = 0\text{ V}$ to 3 V	85	110		dB
		$V_{CM} = 0\text{ V}$ to 3 V , $T_A = -40^\circ\text{C}$ to 125°C	80			dB
Output Characteristics						
	Output Voltage Swing from Positive Rail	$R_L = 10\text{ k}\Omega$ to $V_S/2$		10	15	mV
		$R_L = 10\text{ k}\Omega$ to $V_S/2$, $T_A = -40^\circ\text{C}$ to 125°C			20	mV
	Output Voltage Swing from Negative Rail	$R_L = 10\text{ k}\Omega$ to $V_S/2$		10	15	mV
		$R_L = 10\text{ k}\Omega$ to $V_S/2$, $T_A = -40^\circ\text{C}$ to 125°C			20	mV

Electrical Characteristics (Continued)

All test condition: $V_S = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$, unless otherwise noted.

Parameter		Conditions	Min	Typ	Max	Unit
I _{sc}	Output Short-Circuit Current	Sink or Source	70	90		mA
		Sink or Source, $T_A = -40^\circ\text{C}$ to 125°C	60			mA
AC Specifications						
GBW	Gain-Bandwidth Product ⁽¹⁾			1.5		MHz
SR	Slew Rate ⁽¹⁾	$G = 1$, 2 V step, $T_A = -40^\circ\text{C}$ to 125°C		0.7		V/ μs
t _s	Settling Time, 0.1% ⁽¹⁾	$G = 1$, 2 V step		4.3		ns
	Settling Time, 0.01% ⁽²⁾	$G = 1$, 2 V step		5.4		ns
PM	Phase Margin ⁽¹⁾	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$		80		°
GM	Gain Margin ⁽¹⁾	$R_L = 10\text{ k}\Omega$, $C_L = 100\text{ pF}$		15		dB
	Channel Separation ⁽¹⁾	$f = 100\text{ kHz}$				dB
Noise Performance						
E _N	Input Voltage Noise ⁽¹⁾	$f = 0.1\text{ Hz}$ to 10 Hz ,		2.1		μV_{RMS}
e _N	Input Voltage Noise Density ⁽¹⁾	$f = 1\text{ kHz}$		22		nV/ $\sqrt{\text{Hz}}$
i _N	Input Current Noise ⁽¹⁾	$f = 1\text{ kHz}$		2		fA/ $\sqrt{\text{Hz}}$
THD+N	Total Harmonic Distortion and Noise ⁽²⁾	$f = 1\text{ kHz}$, $G = 1$, $R_L = 10\text{ k}\Omega$, $V_{\text{OUT}} = 1\text{ V}_{\text{RMS}}$		0.002		%

(1) Provided by bench test and design simulation.

(2) Provided by design simulation.

Typical Performance Characteristics

All test condition: $V_S = 5\text{ V}$, $V_{CM} = 2.5\text{ V}$, unless otherwise noted.

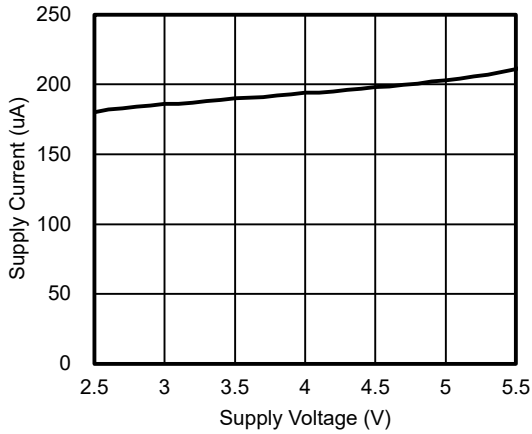


Figure 1. Supply Current vs Supply Voltage

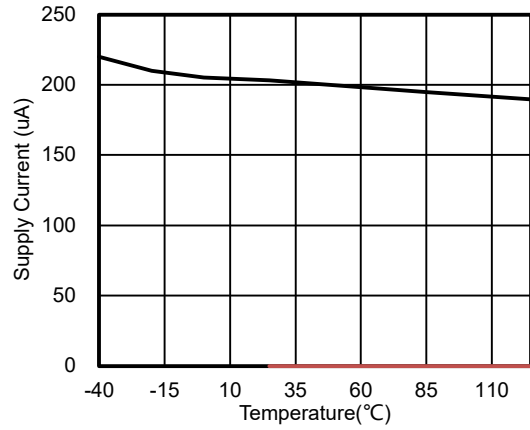


Figure 2. Supply Current vs Temperature

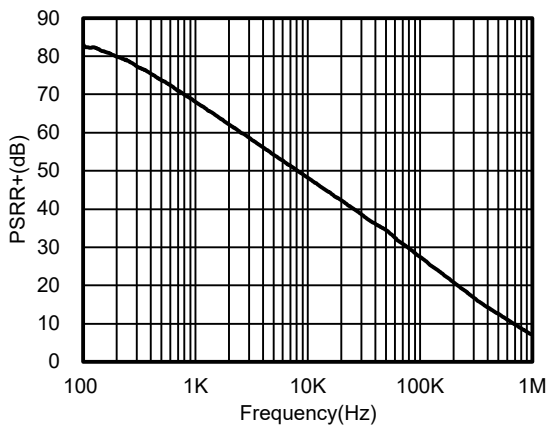


Figure 3. PSRR+ vs Frequency

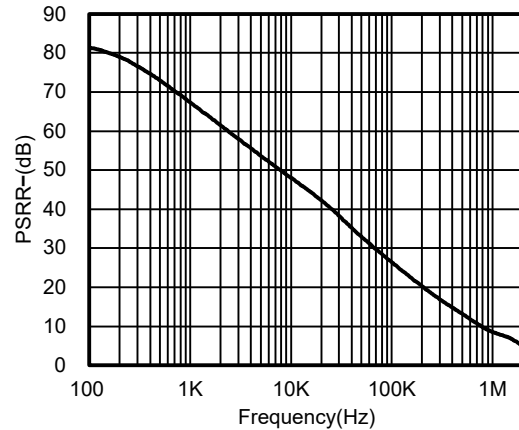


Figure 4. PSRR- vs Frequency

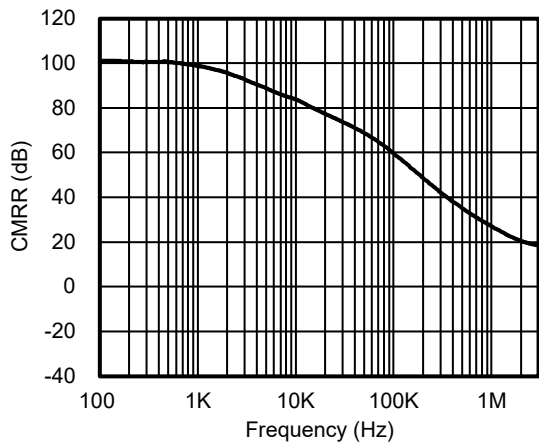


Figure 5. CMRR vs Frequency

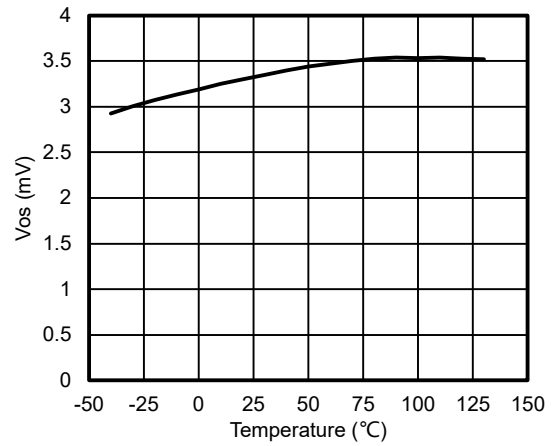


Figure 6. Open Loop Gain and Phase Margin vs Frequency, $R_L = 10\text{ k}\Omega$

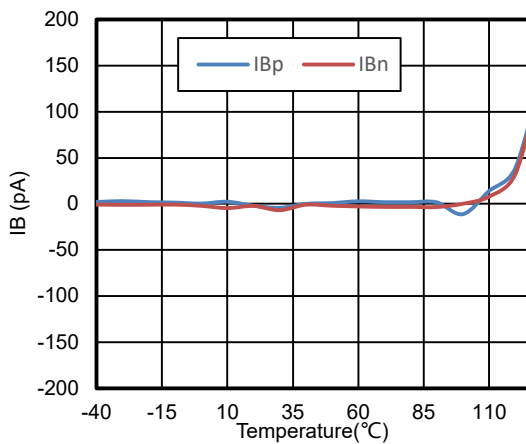


Figure 7. I_B vs Temperature

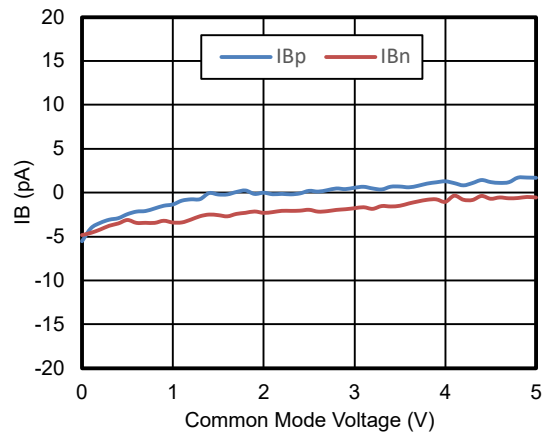


Figure 8. I_B vs V_{CM} , $V_S = 5\text{ V}$

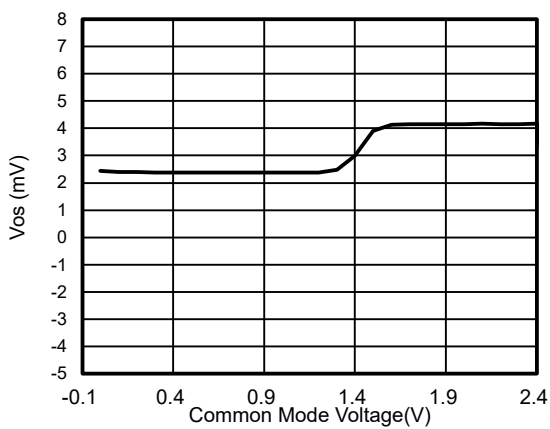


Figure 9. V_{OS} vs V_{CM} , $V_S = 2.5\text{ V}$

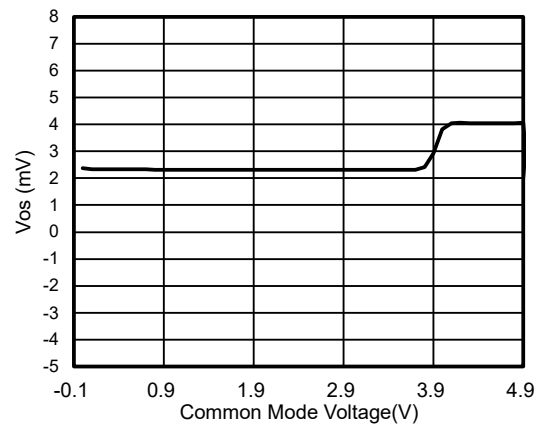
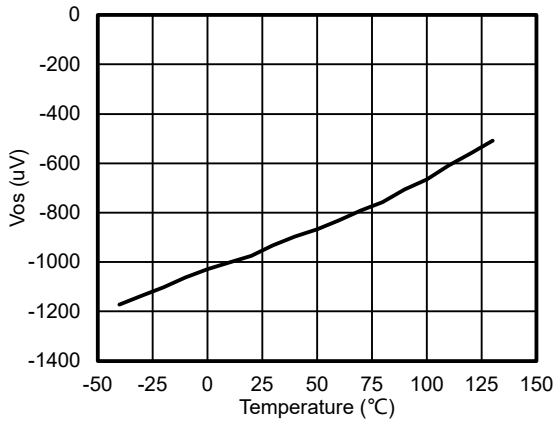
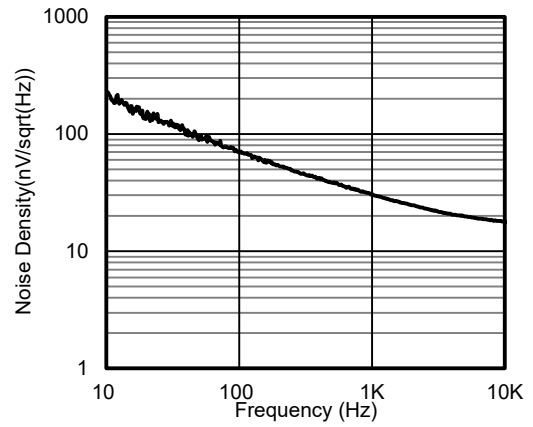
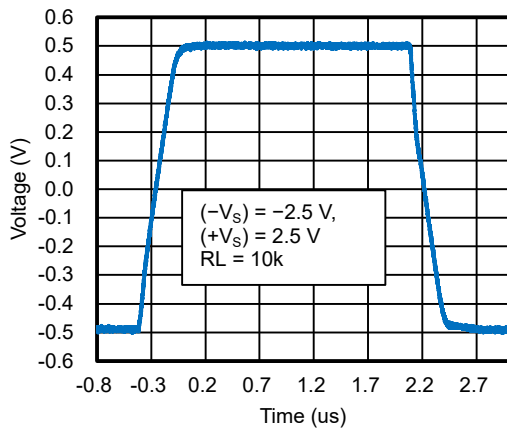
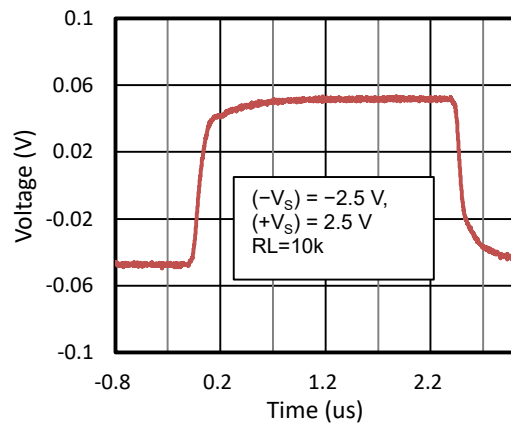
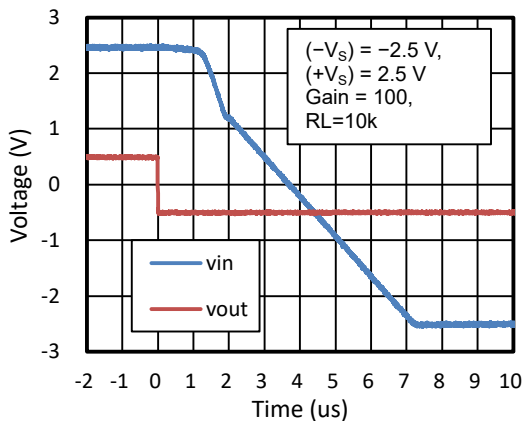
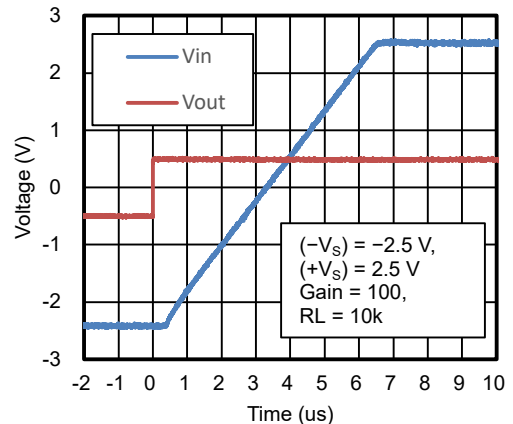


Figure 10. V_{OS} vs V_{CM} , $V_S = 5\text{ V}$

5-V, Rail-to-Rail Input/Output, 1.5-MHz Op Amp

Figure 11. Vos vs Temperature

Figure 12. Voltage Noise Spectral Density vs Frequency, $V_{CM} = 2.5 V$

Figure 13. Large Signal Step Response

Figure 14. Small Signal Step Response

Figure 15. Overload Recovery at Negative Rail

Figure 16. Overload Recovery at Positive Rail

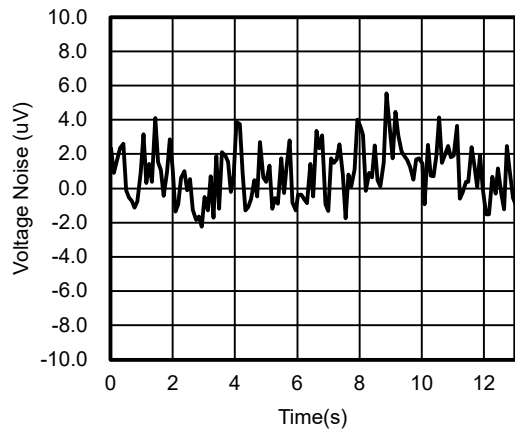
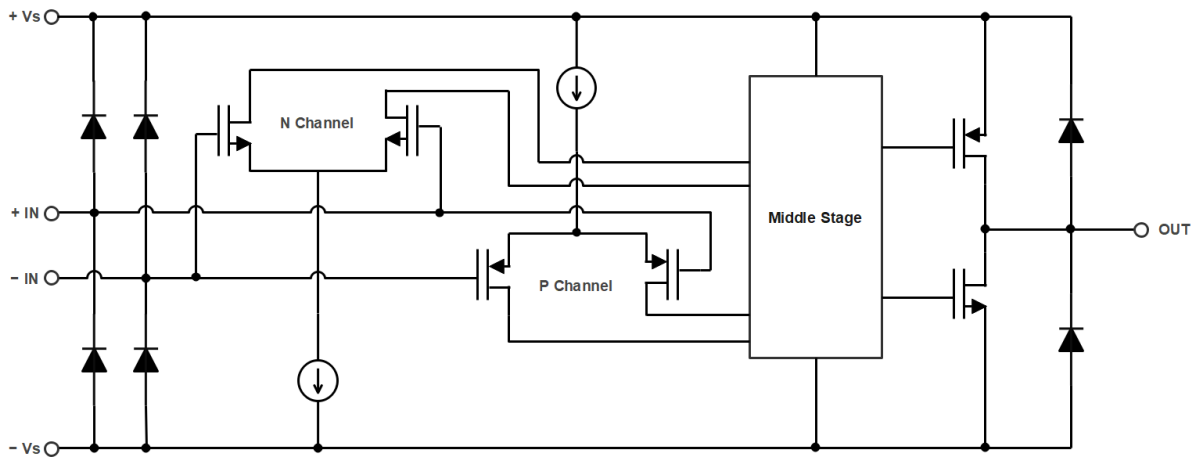


Figure 17. 0.1 to 10 Hz Voltage Noise, $V_{CM} = 2.5\text{ V}$

Detailed Description**Functional Block Diagram****Figure 18. Functional Block Diagram**

Application and Implementation

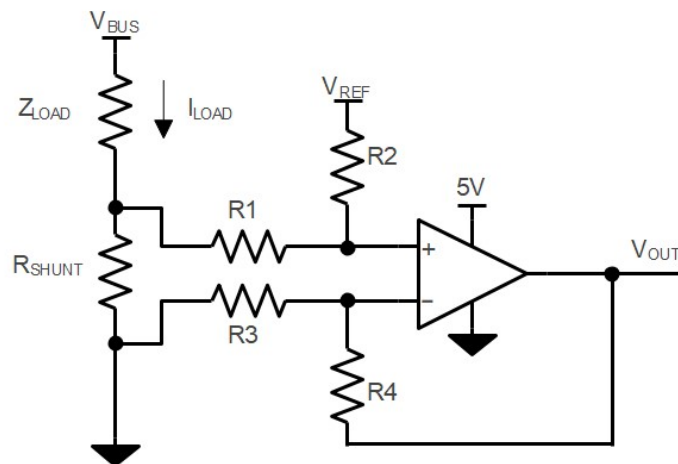
Note

Information in the following application sections is not part of the 3PEAK's component specification and 3PEAK does not warrant its accuracy or completeness. 3PEAK's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

Application Information

Low-Side Current Sensing Application

The following figure shows the device configured in a low-side current sensing application. The low-side current sensing method consists of placing a sense resistor between the load and the circuit ground. The voltage dropping across the resistor is amplified by different amplifier circuits with the device. The V_{REF} can be used to add bias voltage to output voltage. Particular attention must be paid to the matching and precision of R1, R2, R3, and R4, to maximize the accuracy of the measurement.

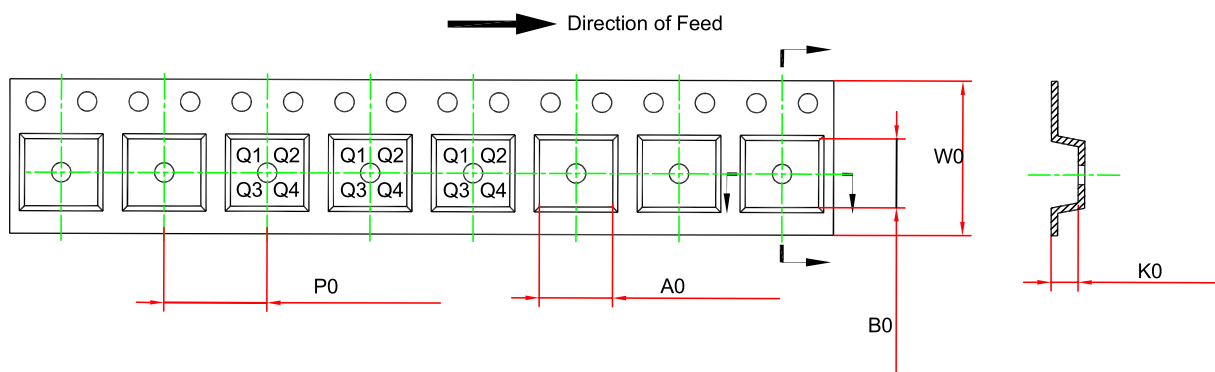
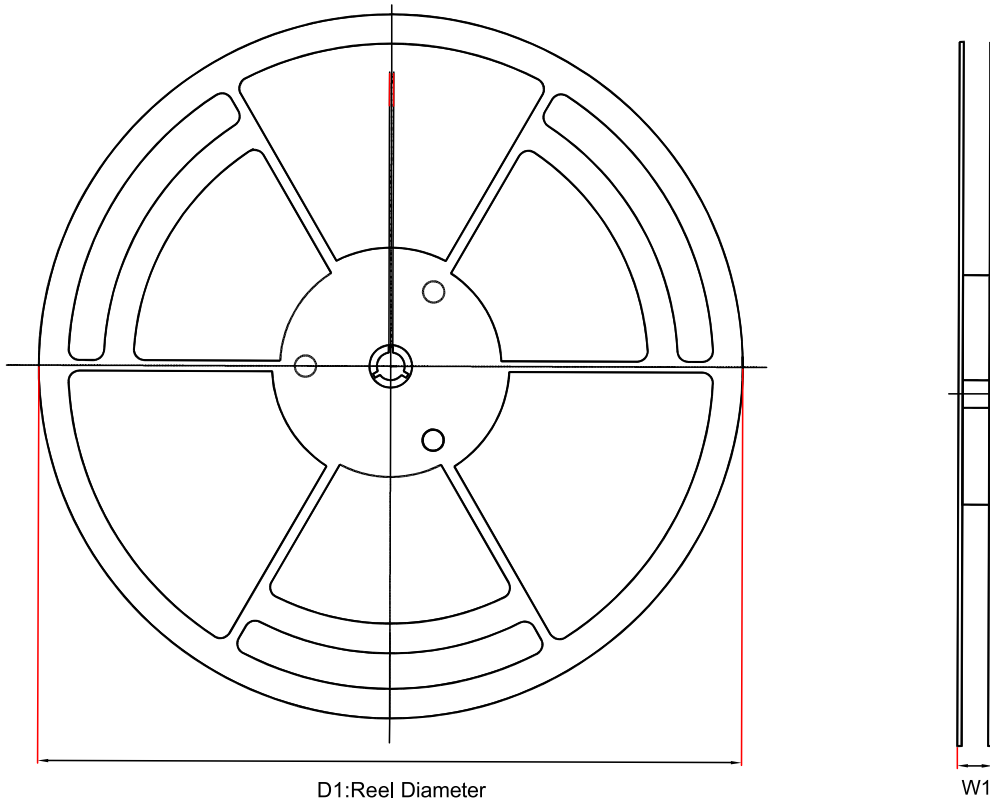


$$V_{OUT} = (I_{LOAD} \times R_{SHUNT}) \times (R2 / R1) + V_{REF}$$

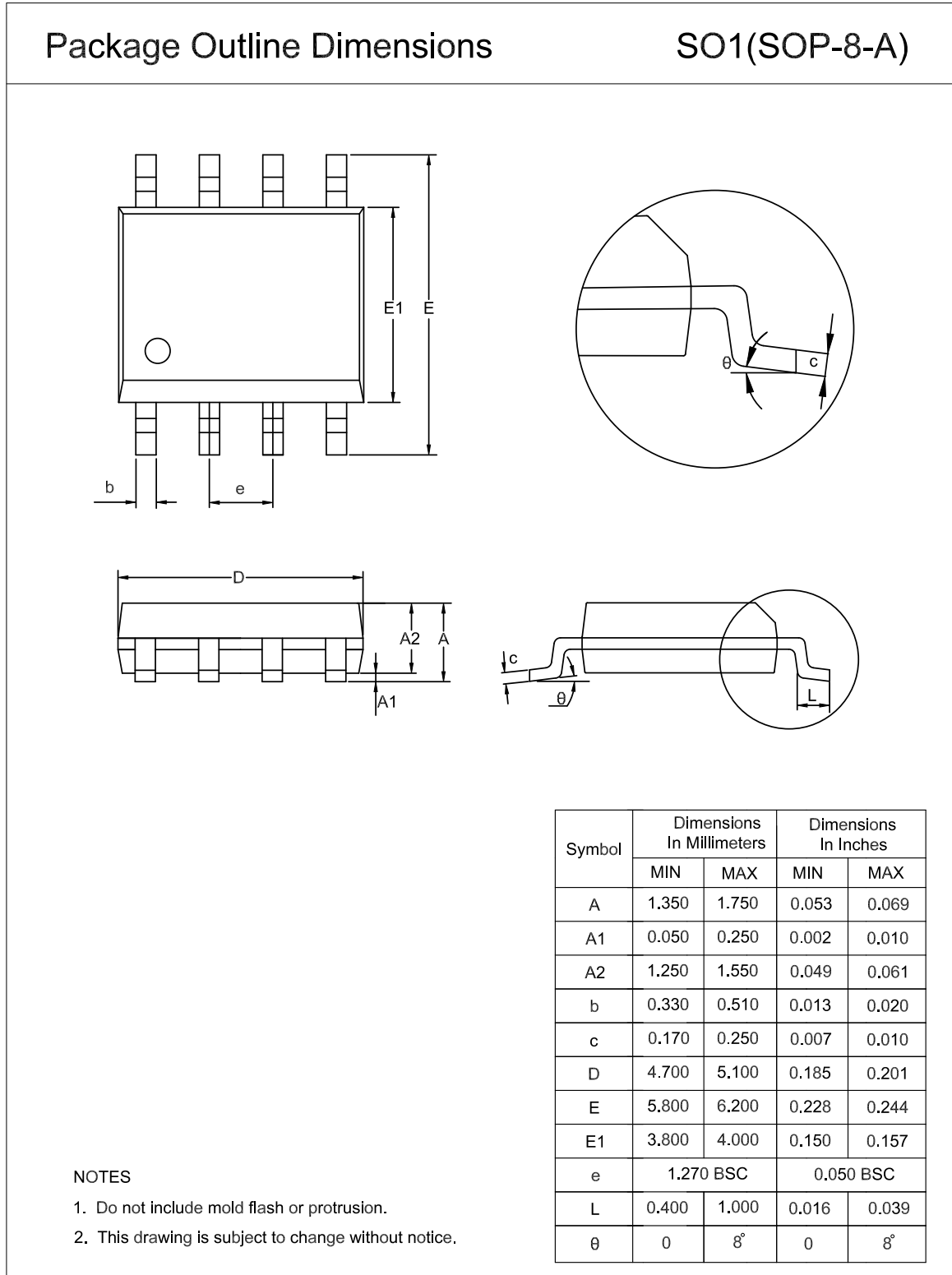
$$\text{When } R3 = R1, R2 = R4, R_{SHUNT} \ll R1$$

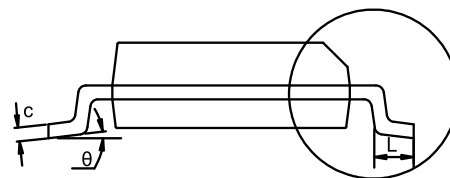
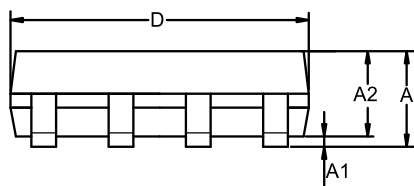
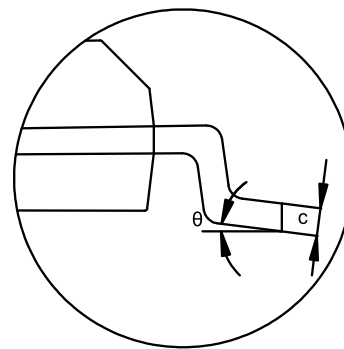
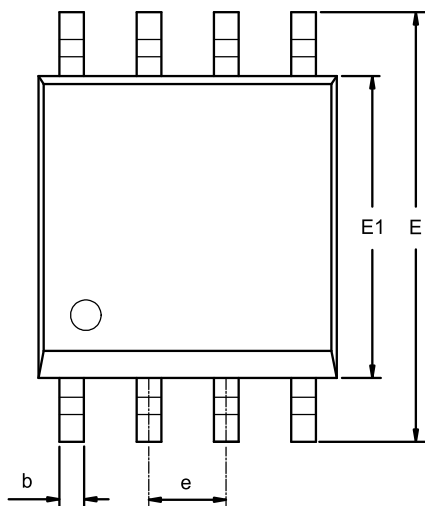
Power Supply Recommendations

Place 0.1- μ F bypass capacitors close to the power-supply pins for reducing coupling errors from the noisy or high impedance power supplies.

Tape and Reel Information


Order Number	Package	D1 (mm)	W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	W0 (mm)	Pin1 Quadrant
LMV358X-SO1R	SOP8	330	17.6	6.5	5.4	2	8	12	Q1
LMV358X-VS1R	MSOP8	330	17.6	5.1	3.3	1.3	8	12	Q1

Package Outline Dimensions
SOP8


MSOP8
Package Outline Dimensions
VS1(MSOP-8-A)


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.800	1.100	0.031	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	4.700	5.100	0.185	0.201
E1	2.900	3.100	0.114	0.122
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0	8°	0	8°

NOTES

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

Order Information

Order Number	Operating Temperature Range	Package	Marking Information	MSL	Transport Media, Quantity	Eco Plan
LMV358X-SO1R	-40 to 125°C	SOP8	V358X	MSL3	Tape and Reel,4000	Green
LMV358X-VS1R	-40 to 125°C	MSOP8	V358X	MSL3	Tape and Reel,3000	Green

Green: 3PEAK defines "Green" to mean RoHS compatible and free of halogen substances.

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